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Automotive P-Channel 60 V (D-S) 175 °C MOSFET

DESCRIPTION

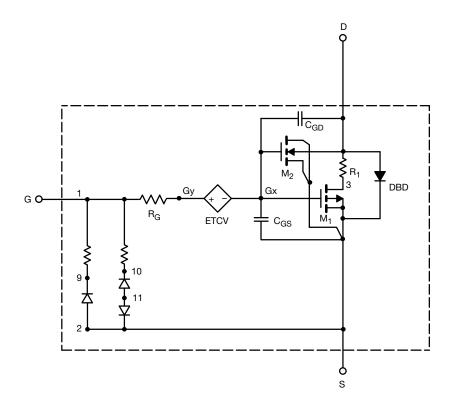
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The sub-circuit model is extracted and optimized over the -55 °C to +125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- P-channel vertical DMOS
- · Macro model (subcircuit model)
- Level 3 MOS
- · Apply for both linear and switching application
- Accurate over the -55 °C to 125 °C temperature range
- · Model the gate charge

SUBCIRCUIT MODEL SCHEMATIC



Note

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer
to the appropriate datasheet of the same number for guaranteed specification limits



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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	2	-	V
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = -10 \text{ V}, I_D = -4.5 \text{ A}$	0.083	0.079	Ω
		$V_{GS} = -4.5 \text{ V}, I_D = -3.5 \text{ A}$	0.122	0.112	
Forward transconductance ^a	9 _{fs}	$V_{DS} = -15 \text{ V}, I_D = -4 \text{ A}$	9	9	S
Diode forward voltage	V_{SD}	I _S = -1.6 A	-0.80	-0.80	V
Dynamic ^b					
Input capacitance	C _{iss}	V _{DS} = -30 V, V _{GS} = 0 V, f = 1 MHz	742	700	pF
Output capacitance	C _{oss}		93	90	
Reverse transfer capacitance	C _{rss}		56	50	
Total gate charge	Q_g	$V_{DS} = -30 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -5 \text{ A}$	15.1	15.3	nC
Gate-source charge	Q _{gs}		3	3.1	
Gate-drain charge	Q_{gd}		3.1	3.5	

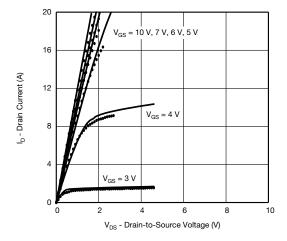
Notes

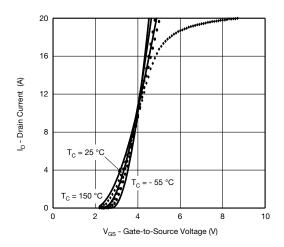
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing

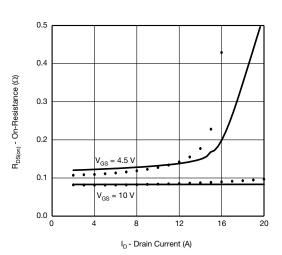
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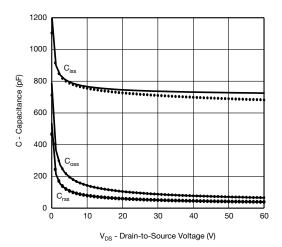
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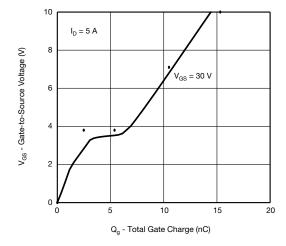
COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25~^{\circ}\text{C}$, unless otherwise noted)

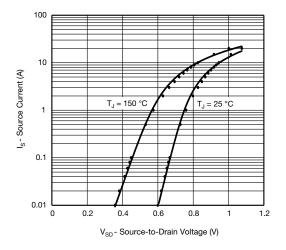












Note

 Dots and squares represent measured data Copyright: Vishay Intertechnology, Inc.



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